TGA2214-CP

2 – 18 GHz 4 W GaN Power Amplifier

Product Description

Qorvo's TGA2214-CP is a packaged wideband power amplifier fabricated on Qorvo's QGaN15 0.15 µm GaN on SiC process. Operating from 2 to 18 GHz, the TGA2214-CP generates > 4 W saturated output power with a power-added efficiency of > 15 %, and > 14 dB large signal gain across the entire operational band.

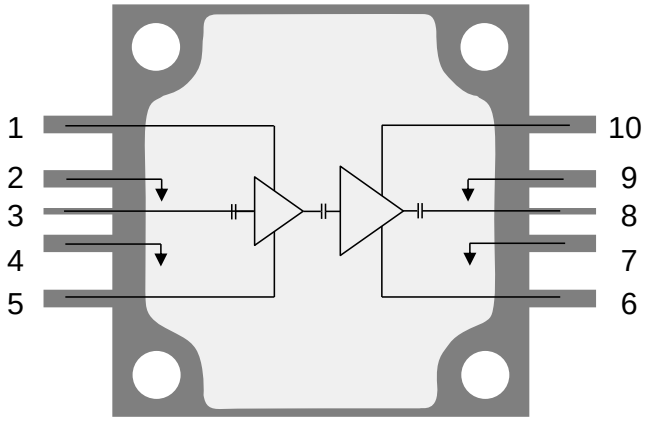
The TGA2214-CP is offered in a 10-lead 15 x 15 mm bolt-down package. The package has a pure Cu base, offering superior thermal management. The TGA2214-CP is ideally suited to support, both in the commercial and the defense arenas, applications requiring either wideband or multi-band frequency performance.

Both RF ports have integrated DC blocking capacitors and are fully matched to 50 Ohms.

Product Features

- Frequency Range: 2 – 18 GHz
- P_{OUT}: > 36 dBm at P_{IN} = 23 dBm
- PAE: > 15 % CW at P_{IN} = 23 dBm
- Small Signal Gain: > 22 dB
- IM3: < −17 dBc at 30 dBm P_{OUT} / Tone
- Bias: V_D = +22 V, I_{DQ} = 600 mA, V_G = −2.3 V Typical
- Package Dimensions: 15.2 x 15.2 x 3.5 mm
- Package base is pure Cu offering superior thermal management

Functional Block Diagram



Applications

- Test Equipment
- Electronic Warfare
- Military and Commercial Radar

Ordering Information

Part No.	Description
TGA2214-CP	2 – 18 GHz 4 W GaN Power Amplifier
1119150	TGA2214-CP Evaluation Board

Absolute Maximum Ratings

Parameter	Value / Range
Drain Voltage (V_D)	+29.5 V
Gate Voltage Range (V_G)	−5 to 0 V
Drain Current (I_D) 1st stage 2nd stage	 0.5 A 1.0 A
Forward Gate Current (I_G)	See page 8
Power Dissipation (P_{DISS}), 85 °C	31 W
Input Power, CW, 50 Ω, (P_{IN})	31 dBm
Input Power, CW, VSWR 3:1, V_D = +30 V, 85 °C, (P_{IN})	31 dBm
Channel Temperature (T_{CH})	275 °C
Soldering Temperature (30 Seconds)	260 °C
Storage Temperature	−55 to 150 °C

Operation of this device outside the parameter ranges given above may cause permanent damage. These are stress ratings only, and functional operation of the device at these conditions is not implied.

Recommended Operating Conditions

Parameter	Min	Typ.	Max	Units
Drain Voltage (V_D)		+22		V
Drain Current, (I_{DQ})		600		mA
Drain Current, RF (I_{D_Drive})	See chart page 6			mA
Gate Voltage Range (V_G)	−2 to -2.9			V
Gate Current, RF (I_{G_Drive})	See chart page 6			mA
T_{BASE} Range	−40		+85	ºC

Electrical specifications are measured at specified test conditions. Specifications are not guaranteed over all recommended operating conditions.

Electrical Specifications

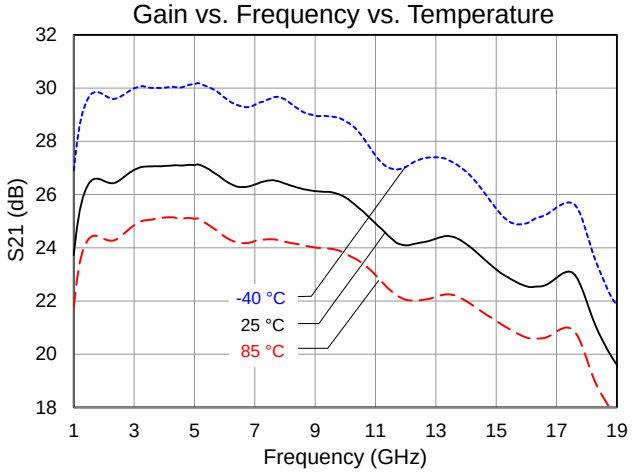
Parameter	Min	Typ	Max	Units
Operational Frequency Range	2	–	18	GHz
Small Signal Gain	–	> 22	–	dB
Input Return Loss	–	> 8	–	dB
Output Return Loss	–	> 11	–	dB
Output Power at P_{IN} = 23 dBm	–	> 36	–	dBm
Power Added Efficiency at P_{IN} = 23 dBm	–	> 15	–	%
IM3 (P_{OUT} / Tone = 30 dBm/Tone)	–	< −17	–	dBc
IM5 (P_{OUT} / Tone = 30 dBm/Tone)	–	< −29	–	dBc
Small Signal Gain Temperature Coefficient	–	-0.04	–	dB/°C
Output Power Temperature Coefficient (25 to 85 °C)	–	−0.005	–	dBm/°C
Recommended Operating Voltage	–	+22	+22	V

Test conditions unless otherwise noted: 25 °C, V_D = +22 V, I_{DQ} = 600 mA, V_G = −2.3 V Typ, CW.

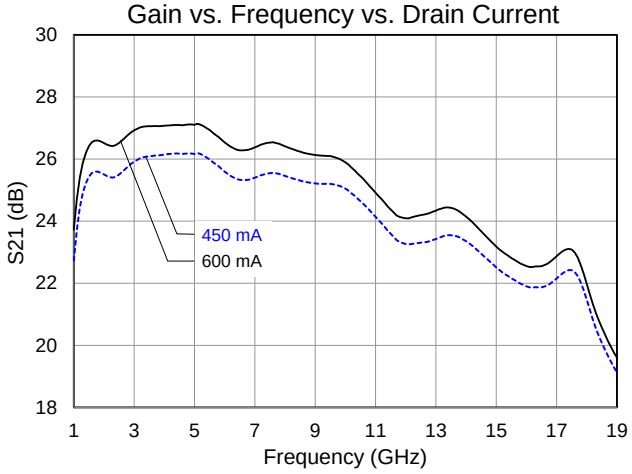
Performance Plots – Small Signal

Conditions unless otherwise specified: V_D = +22 V, I_{DQ} = 600 mA, V_G = −2.3 V Typical, CW.

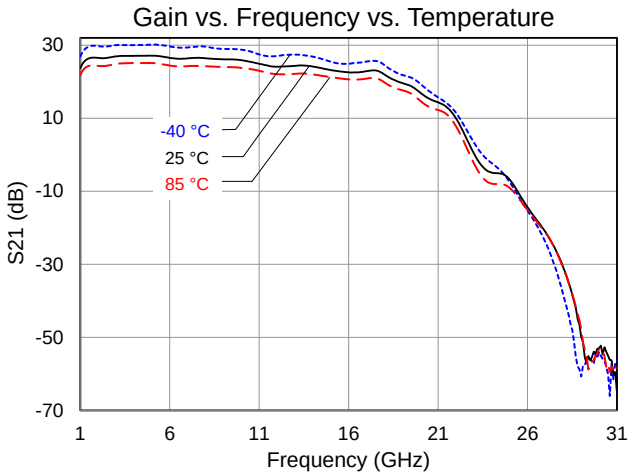
Gain vs. Frequency vs. Temperature



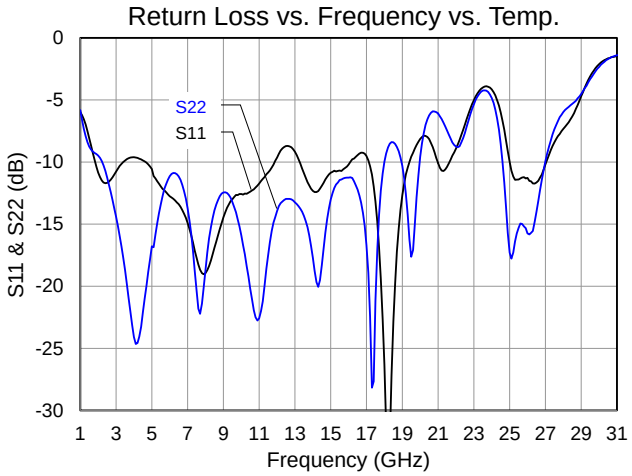
Gain vs. Frequency vs. Drain Current



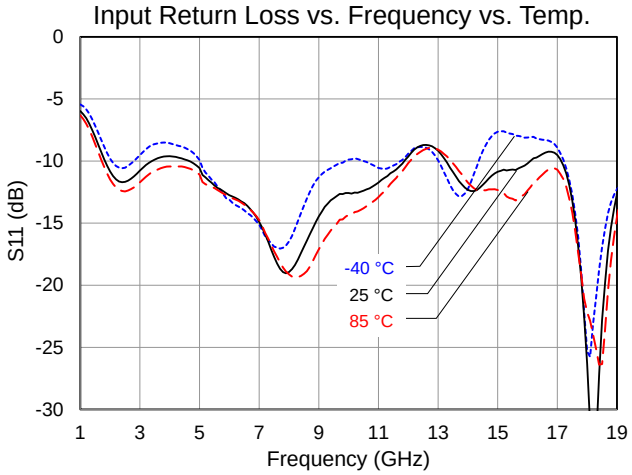
Gain vs. Frequency vs. Temperature



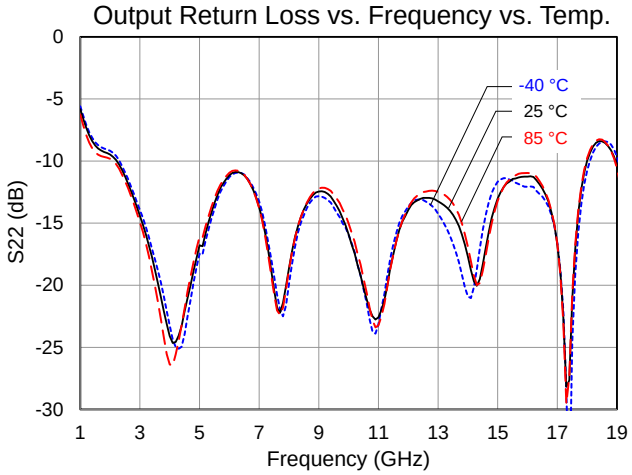
Return Loss vs. Frequency vs. Temp.



Input Return Loss vs. Frequency vs. Temp.



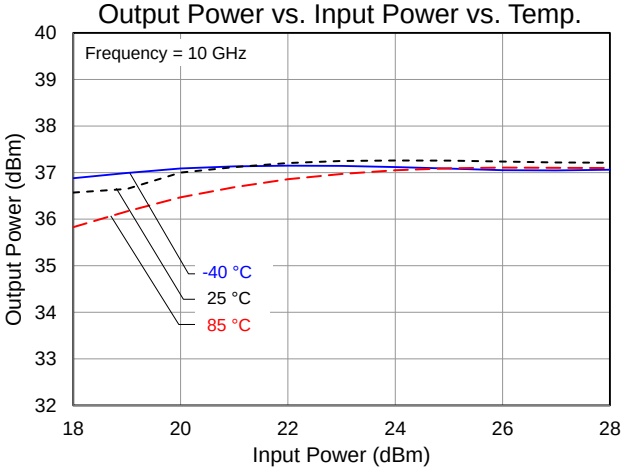
Output Return Loss vs. Frequency vs. Temp.



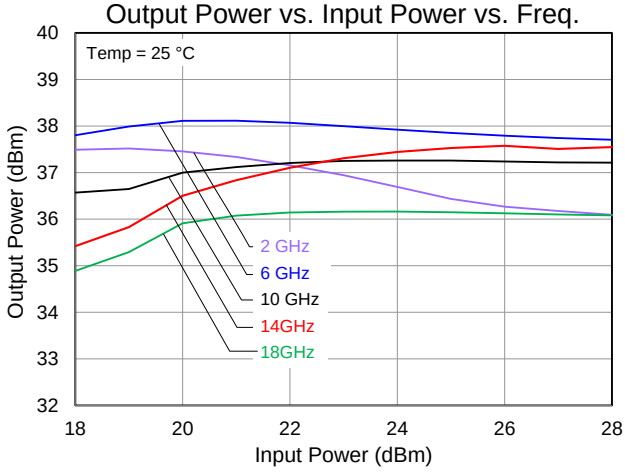
Performance Plots – Large Signal

Conditions unless otherwise specified: V_D = +22 V, I_{DQ} = 600 mA, V_G = −2.3 V Typical, CW.

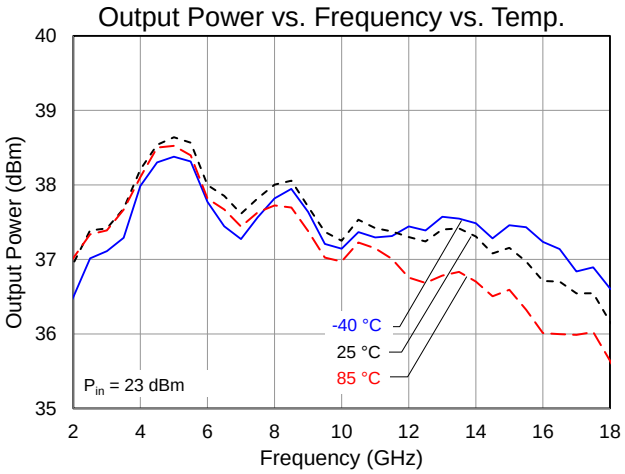
Output Power vs. Input Power vs. Temp.



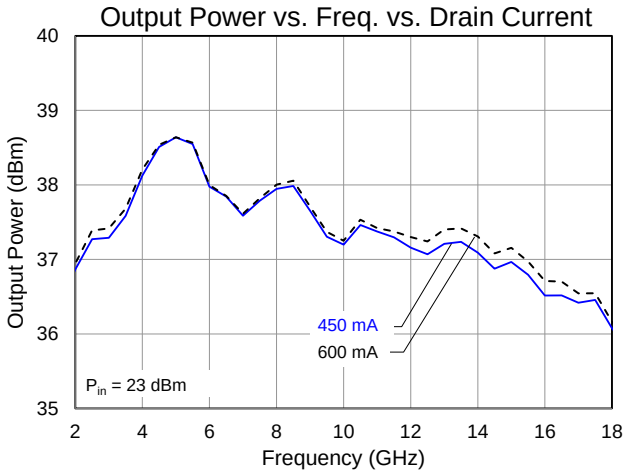
Output Power vs. Input Power vs. Freq.



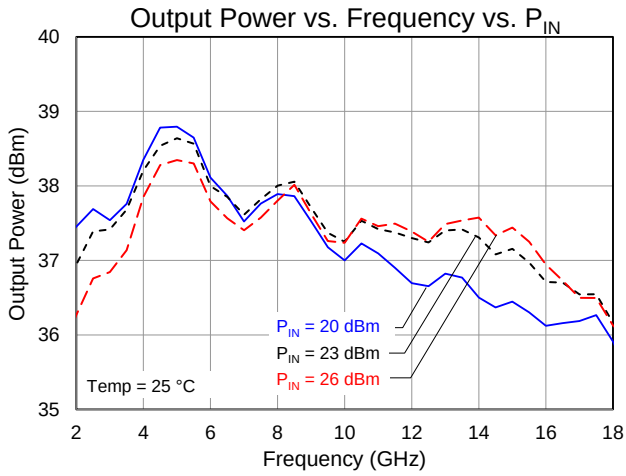
Output Power vs. Frequency vs. Temp.



Output Power vs. Freq. vs. Drain Current



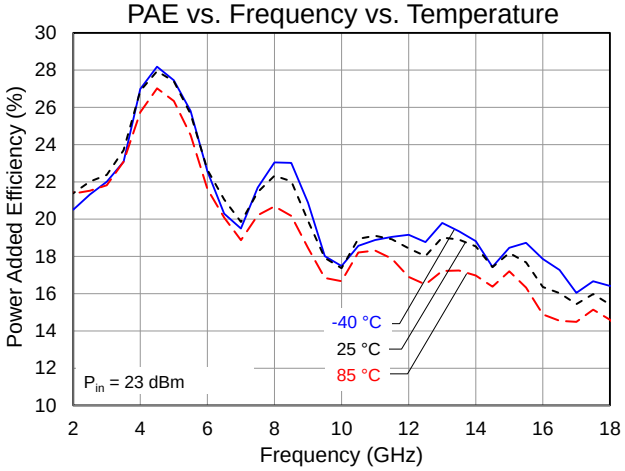
Output Power vs. Frequency vs. P_{IN}



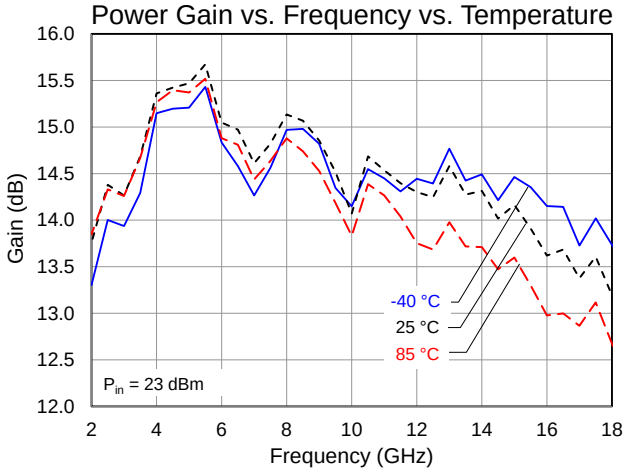
Performance Plots – Large Signal

Conditions unless otherwise specified: V_D = +22 V, I_{DQ} = 600 mA, V_G = −2.3 V Typical, CW.

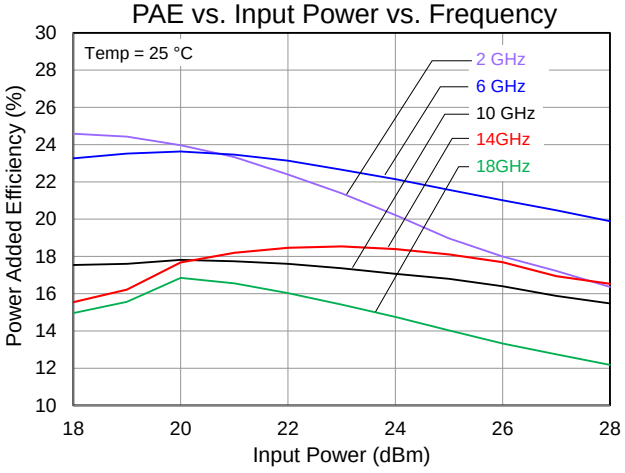
PAE vs. Frequency vs. Temperature



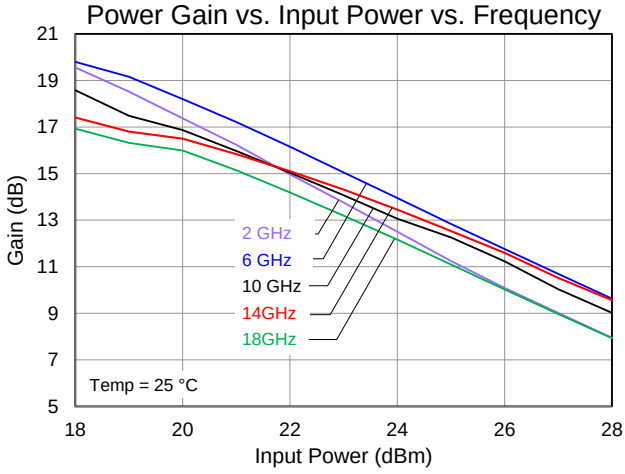
Power Gain vs. Frequency vs. Temperature



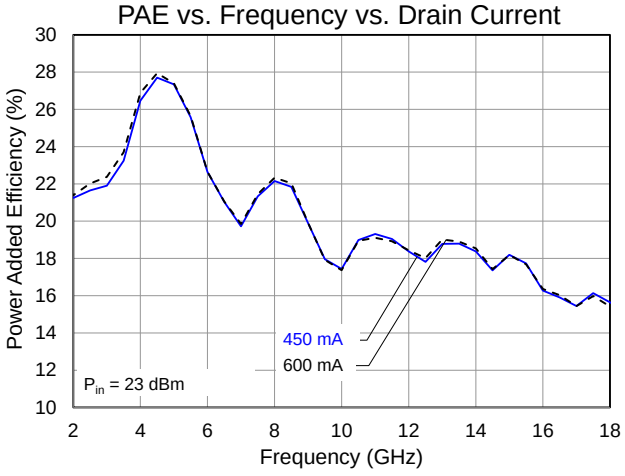
PAE vs. Input Power vs. Frequency



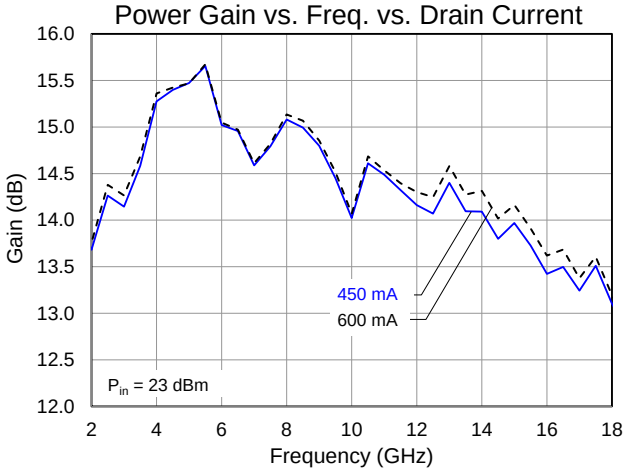
Power Gain vs. Input Power vs. Frequency



PAE vs. Frequency vs. Drain Current

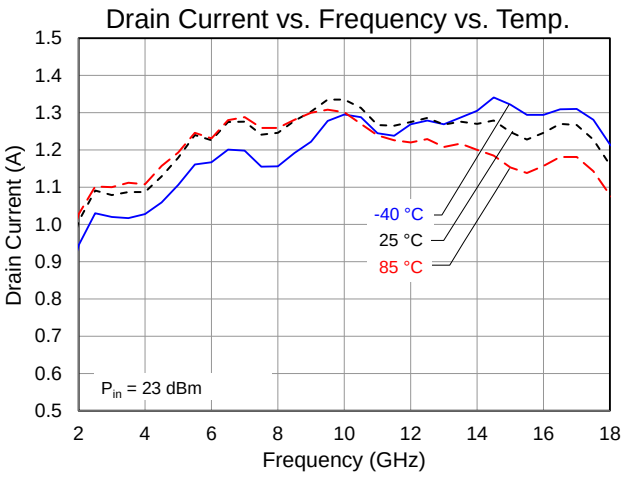


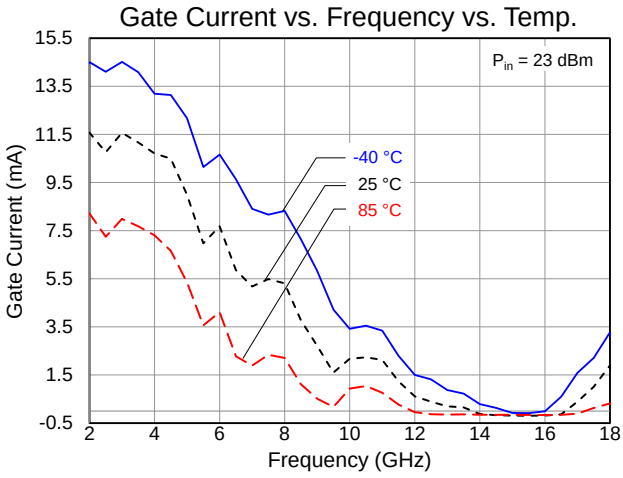
Power Gain vs. Freq. vs. Drain Current

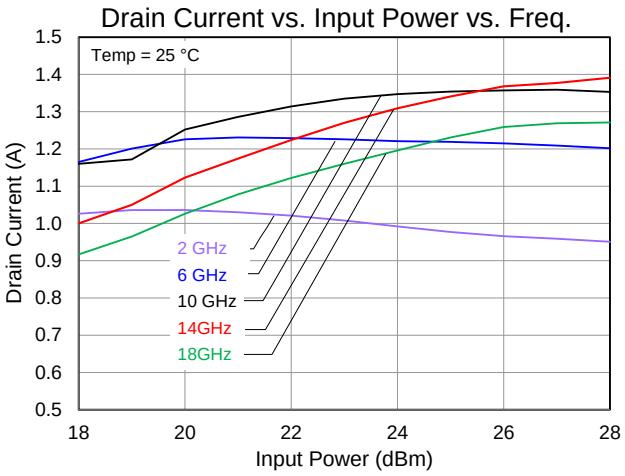


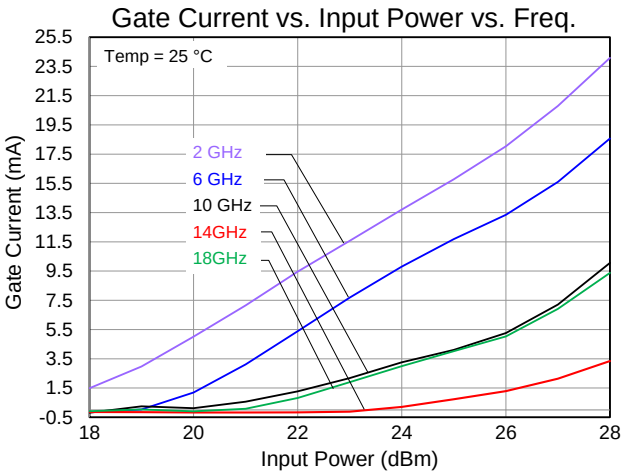
Performance Plots – Large Signal

Conditions unless otherwise specified: V_D = +22 V, I_{DQ} = 600 mA, V_G = −2.3 V Typical, CW.





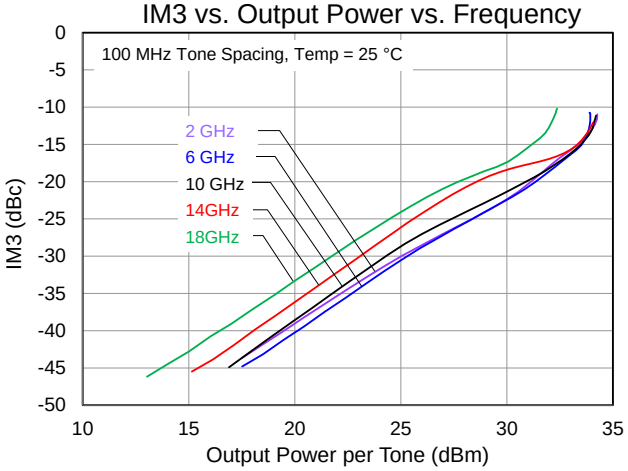




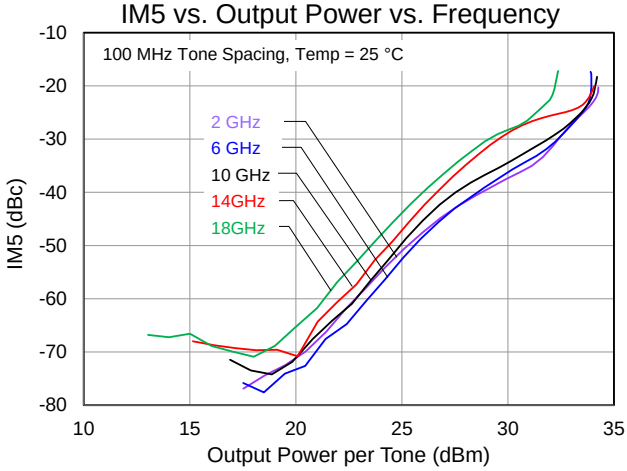
Performance Plots – Linearity

Conditions unless otherwise specified: V_D = +22 V, I_{DQ} = 600 mA, V_G = −2.3 V Typical, CW.

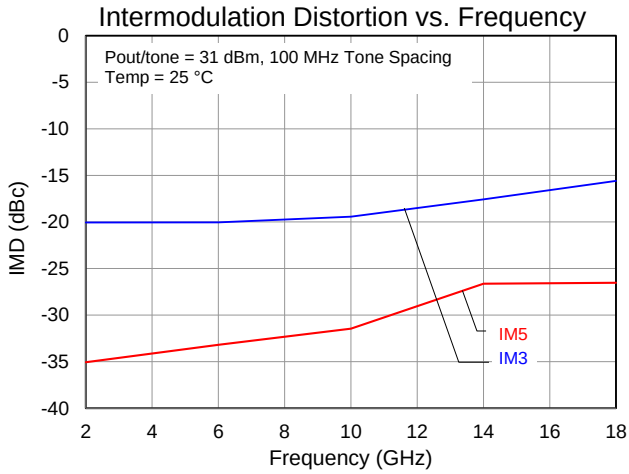
IM3 vs. Output Power vs. Frequency



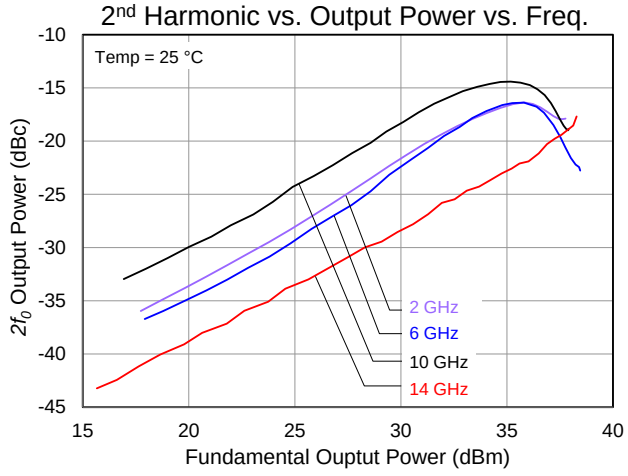
IM5 vs. Output Power vs. Frequency



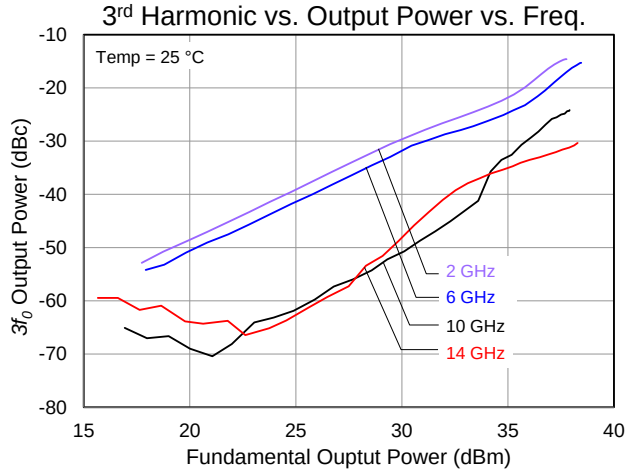
Intermodulation Distortion vs. Frequency



2nd Harmonic vs. Output Power vs. Freq.



3rd Harmonic vs. Output Power vs. Freq.

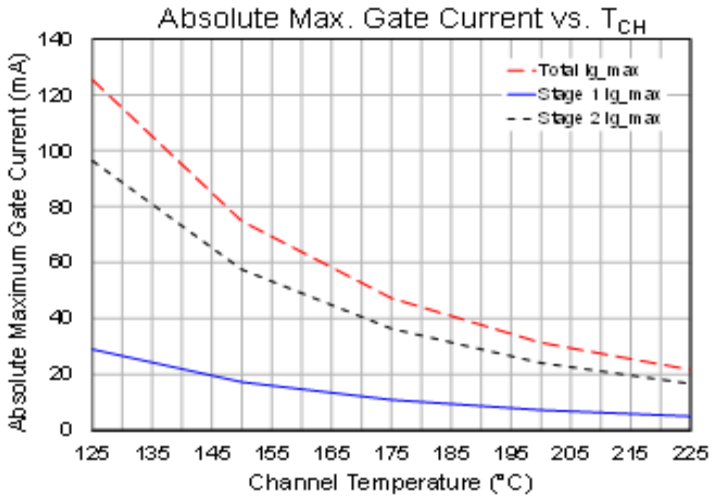


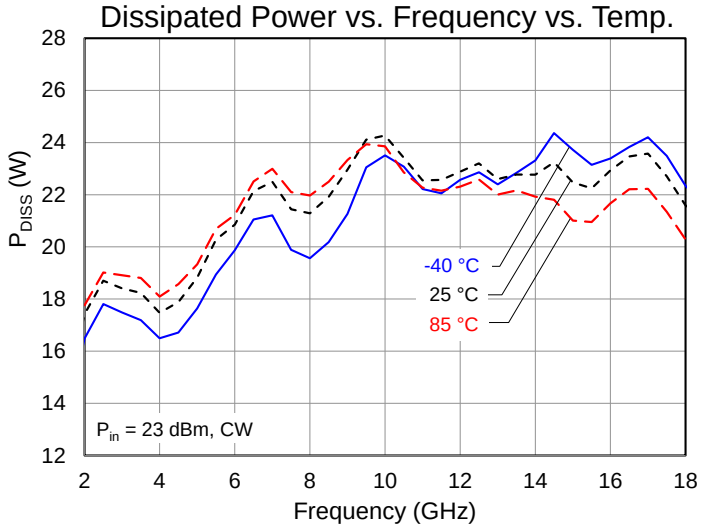
Thermal and Reliability Information

Parameter	Test Conditions	Value	Units
Thermal Resistance (θ_{JC}) (1)	V_D = +22 V, I_{DQ} = 600 mA, T_{BASE} = 85 °C, CW Freq = 10 GHz, P_{IN} = 23 dBm, P_{OUT} = 37 dBm, P_{DISS} = 23.6 W, I_{D_Drive} = 1.3 A	3.98	°C/W
Channel Temperature (T_{CH}) (under RF) (2)		179	°C

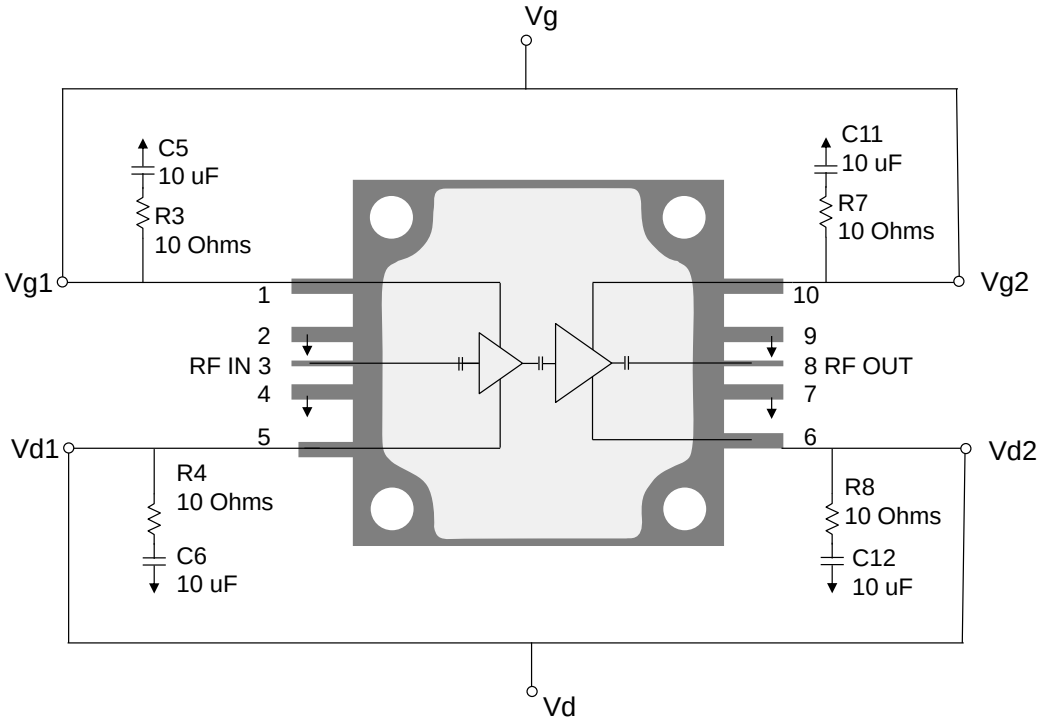
Notes:
1. Thermal resistance is referenced to the back of package (85 °C)
2. Refer to the following document: GaN Device Channel Temperature, Thermal Resistance, and Reliability Estimates

Dissipated Power and Maximum Gate Current





Applications Information and Pin Layout



Bias Up Procedure

1. Set I_D limit to 1.5 A, I_G limit to 26 mA
2. Apply −5 V to V_G
3. Apply +22 V to V_D; ensure I_{DQ} is approx. 0 mA
4. Adjust V_G until I_{DQ} = 600 mA (V_G ~ −2.3 V Typ.).
5. Turn on RF supply

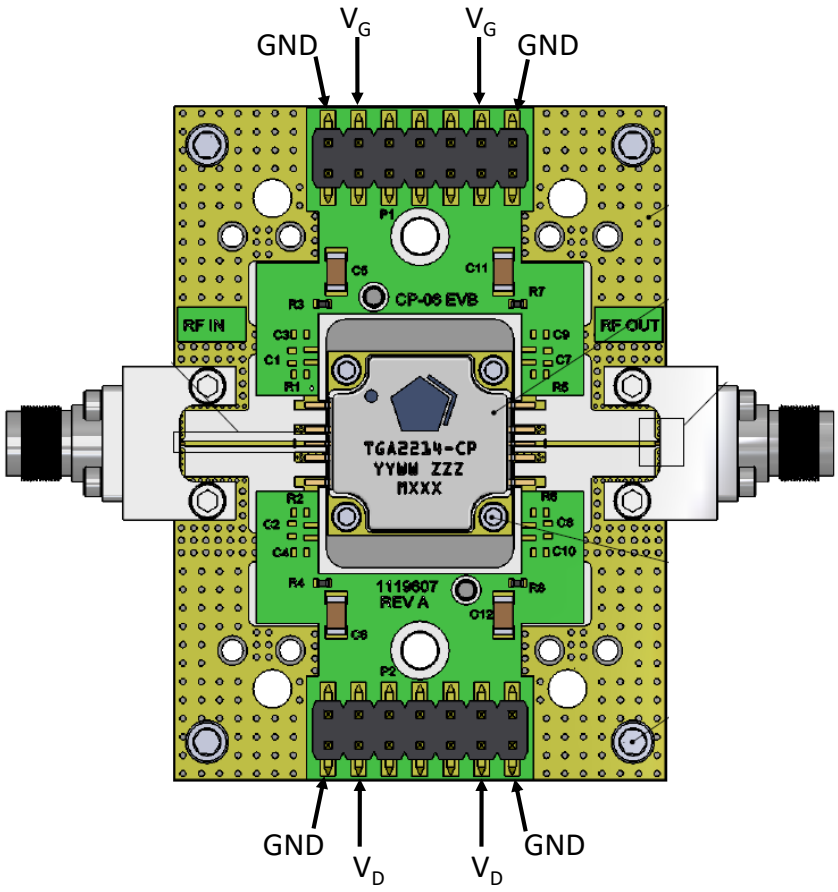
Bias Down Procedure

1. Turn off RF supply
2. Reduce V_G to −5 V; ensure I_{DQ} is approx. 0 mA
3. Set V_D to 0 V
4. Turn off V_D supply
5. Turn off V_G supply

Pad Description

Pin No.	Symbol	Description
1,10	V_{G1}, V_{G2} (respectively)	Gate Voltage; Bias network is required; must be biased from both sides; see recommended Application Information above.
2,4,7,9	GND	Must be grounded on the PCB
3	RF_{IN}	Output; matched to 50 Ω; DC blocked
5,6	V_{D1}, V_{D2} (respectively)	Drain voltage; Bias network is required; must be biased from both sides; see recommended Application Information above.
8	RF_{OUT}	Input; matched to 50 Ω; DC blocked

Evaluation Board



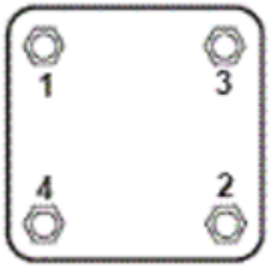
Notes:
1. PCB is made from Rogers 4003C dielectric, 0.008 inch thick, 0.5 oz. copper both sides.
2. Both V_D and V_G pins must be biased.

Bill of Materials

Reference Des.	Value	Description	Manuf.	Part Number
C5, C6, C11, C12	10 µF	Cap, 1206, +50 V, 20 %, X5R	Various	–
R3, R4, R7, R8	10 Ohm	Res, 0402, 5 %	Various	–

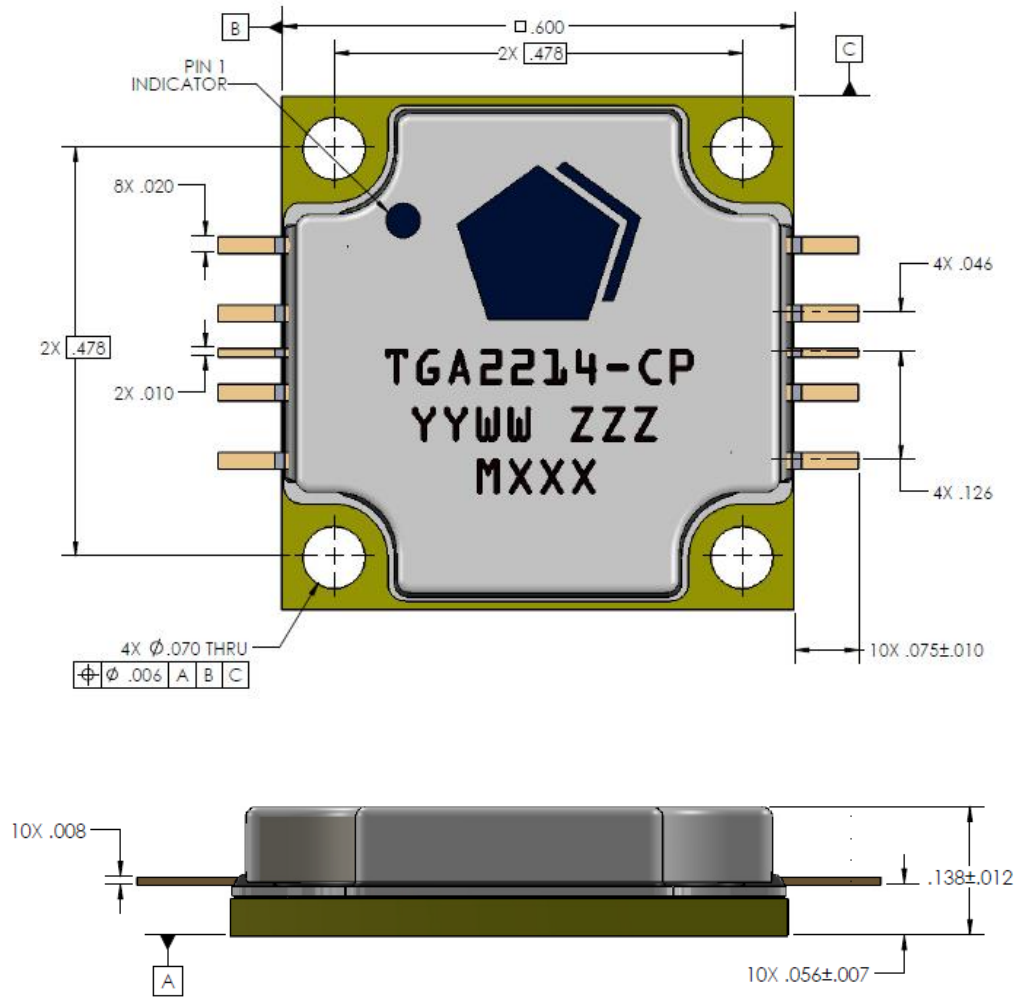
Assembly Notes

1. Carefully clean the PC board and package leads with alcohol. Allow it to dry fully.
2. To improve the thermal and RF performance, Qorvo recommends attaching a heat sink to the bottom of the PCB and apply thermal compound (Arctic Silver 5 recommended) or 4 mil indium shim between the heat sink and the package.
3. (The following is for *information only*. There are many variables in a second level assembly that Qorvo does not control, so Qorvo does not recommend an absolute torque value.) Use screws to attach the component to the heat sink. A suggested torque value is 16 in-oz. for a 0-80 screw. Start with screws finger tight, then torque to 8 in-oz., then torque to final value. Use the following tightening pattern:



4. Apply no-flux solder to each pin of the TGA2214-CP. The component leads should be manually soldered, and the package cannot be subjected to conventional reflow processes. The use of no-clean solder to avoid washing after soldering is recommended.

Mechanical Information and Marking



Units: inches
Tolerances: unless specified
x.xx = ± 0.01
x.xxx = ± 0.005
Materials:
Base: Copper
Lid: Plastic
All metalized features are gold plated
Part is epoxy sealed
Marking:
2214: Part number
YY: Part Assembly year
WW: Part Assembly week
ZZZ: Serial Number
MXXX: Batch ID

Handling Precautions

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 0B	ANSI/ESD/JEDEC JS-001
MSL – Moisture Sensitivity Level	N/A	

Caution!
ESD-Sensitive Device

Solderability

Compatible with the latest version of J-STD-020, Lead-free solder, 260 °C

RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU. This product also has the following attributes:

- Product uses RoHS Exemption 7c-I to meet RoHS compliance requirements
- Halogen Free (Chlorine, Bromine)
- Antimony Free
- TBBP-A ($C_{15}H_{12}Br_40_2$) Free
- PFOS Free
- SVHC Free

Contact Information

For the latest specifications, additional product information, worldwide sales and distribution locations:

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Tel: 1-844-890-8163

Email: customer.support@qorvo.com

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Поставка электронных компонентов

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Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «**JONHON**», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «**FORSTAR**».

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